

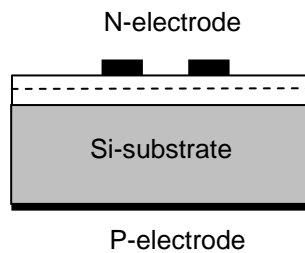
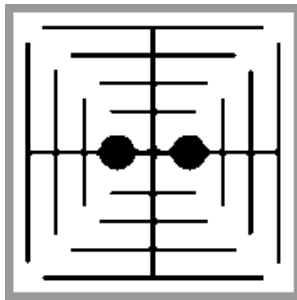
> Mechanical Specification:

(1) Dimension

- Chip size: 42 mil x 42 mil (1066±25 μm x 1066±25 μm)
- Thickness: 6.7 mil (170±25 μm)
- N bonding pad: 5.0 mil (127±10 μm)

(2) Metallization

- Topside N electrode (x2): Au alloy
- Backside P electrode: Au alloy



Features:

- High radiant flux
- Thin film structure
- Vertical electrode
- High driving current

Applications:

- Automotive
- Data Communication
- Surveillance

> Electro-optical Characteristics at 25°C:

Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit	
Forward Voltage	Vf1	If = 10μA	0.7	-	-	V	
	Vf2	If = 350mA	-	1.4	1.8	V	
Reverse Current	Ir	Vr = 10V	-	-	5.0	μA	
Peak Wavelength ⁽¹⁾	λp	If = 350mA	925	940	955	nm	
Spectra Half-width	Δλ	If = 350mA	-	30	-	nm	
Radiant flux ⁽²⁾⁽³⁾	Po	H11	If = 350mA	160	-	-	mW
		H12		190	-	-	

Note:

(1) Basically, the wavelength span is 30nm; however, customers' special requirements are also welcome.

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(3) Radiant flux is measured by EPISTAR's equipment on bare chips.

> Absolute Maximum Ratings:

Parameter	Symbol	Condition	Rating	Unit
Forward DC Current	If	Ta = 25°C	≤ 1000	mA
Reverse Voltage	Vr	Ta = 25°C	≤ 10	V
Junction Temperature	Tj	-	≤ 115	°C
Storage Temperature	Tstg	Chip	-40 ~ +85	°C
		Chip-on-tape/storage	5 ~ 35	°C
		Chip-on-tape/transportation	-20 ~ +65	°C
Temperature during Packaging	-	-	280(<10sec)	°C

Note: Maximum ratings are package dependent. The above maximum ratings were determined using a Metal Core Printed Circuit Board (MCPCB) without an encapsulant. Stresses in excess of the absolute maximum ratings such as forward current and junction temperature may cause damage to the LED.

> Characteristic Curves:

Fig.1 – Relative luminous Intensity vs. Forward Current

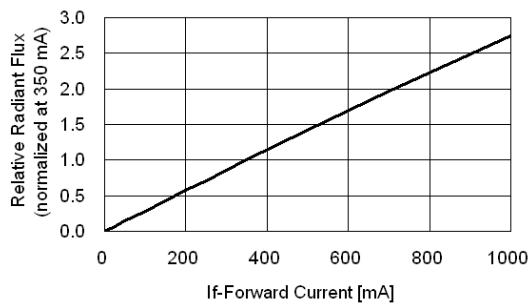


Fig.2 – Forward Current vs. Forward Voltage

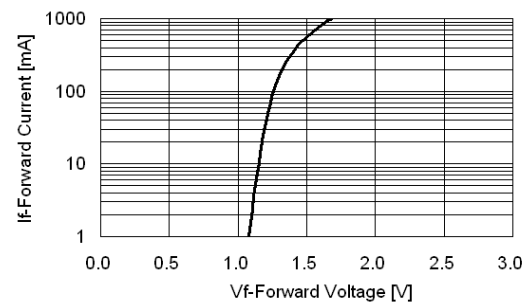


Fig.3 – Relative Radiant Flux (@350mA) vs. Ambient Temperature

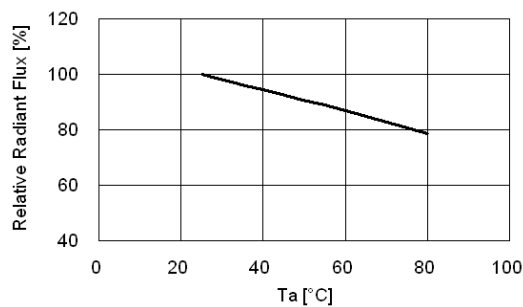


Fig.4 – Forward Voltage (@350mA) vs. Ambient Temperature

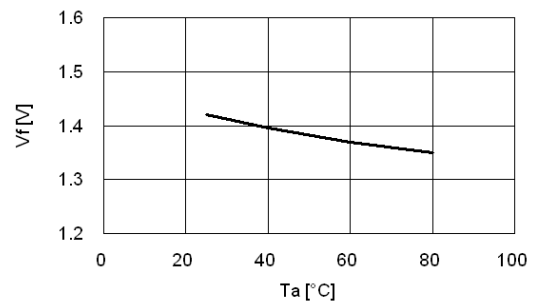


Fig.5 – Peak Wavelength (@350mA) vs. Ambient Temperature

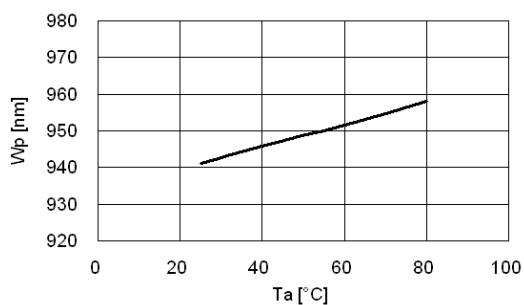


Fig.6 – Maximum Driving Forward DC Current vs. Ambient Temperature (De-rating based on Tj max. = 115°C)

